

EMH9FHA / UMH9NFHA / IMH9AFRA

NPN 100mA 50V Complex Digital Transistors (Bias Resistor Built-in Transistors)

Datasheet

AEC-Q101 Qualified

Parameter	Tr1 and Tr2
V _{CC}	50V
I _{C(MAX.)}	100mA
R ₁	10kΩ
R_2	47 k Ω

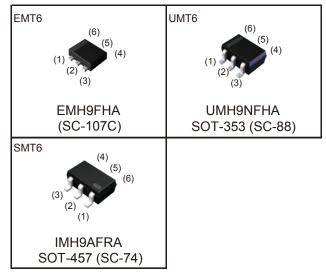
Features

- 1) Built-In Biasing Resistors.
- 2) Two DTC114Y chips in one package.
- 3) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit).
- 4) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 5) Only the on/off conditions need to be set for operation, making the circuit design easy.
- 6) Lead Free/RoHS Compliant.

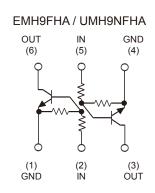
Application

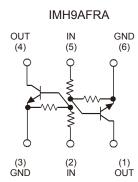
Inverter circuit, Interface circuit, Driver circuit

Outline



•Inner circuit





Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
EMH9FHA	EMT6	1616	T2R	180	8	8,000	H9
UMH9NFHA	UMT6	2021	TR	180	8	3,000	H9
IMH9AFRA	SMT6	2928	T108	180	8	3,000	H9

● Absolute maximum ratings (Ta = 25°C)

<For Tr1 and Tr2 in common>

Paramete	r	Symbol	Values	Unit
Supply voltage	V_{CC}	50	V	
Input voltage	V_{IN}	−6 to +40	V	
Output current	Io	70	mA	
Collector current	I _{C(MAX.)} *1	100	mA	
Power dissipation EMH9FHA / UMH9NFHA IMH9AFRA		P _D *2	150 (Total) ^{*3}	mW
		P_{D}	300 (Total)*4	mW
Junction temperature	T _j	150	°C	
Range of storage temperature		T_{stg}	−55 to +150	°C

●Electrical characteristics(Ta = 25°C)

<For Tr1 and Tr2 in common>

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input voltage	$V_{I(off)}$	$V_{CC} = 5V, I_{O} = 100 \mu A$	-	-	0.3	V
	V _{I(on)}	$V_{\rm O} = 0.3 V, I_{\rm O} = 1 \text{mA}$	1.4	-	-	V
Output voltage	V _{O(on)}	I _O / I _I = 5mA / 0.25mA	-	0.1	0.3	V
Input current	I _I	V ₁ = 5V	-	-	0.88	mA
Output current	I _{O(off)}	$V_{CC} = 50V, V_{I} = 0V$	-	-	0.5	μΑ
DC current gain	G _I	$V_O = 5V$, $I_O = 5mA$	68	-	-	-
Input resistance	R ₁	-	7	10	13	kΩ
Resistance ratio	R ₂ /R ₁	-	3.7	4.7	5.7	-
Transition frequency	f _T *1	$V_{CE} = 10V, I_{E} = -5mA,$ f = 100MHz	-	250	-	MHz

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^{*1} Characteristics of built-in transistor

^{*2} Each terminal mounted on a reference footprint

^{*3 120}mW per element must not be exceeded.

^{*4 200}mW per element must not be exceeded.

●Electrical characteristic curves(Ta = 25°C)

Fig.1 Input voltage vs. output current (ON characteristics) 100 Vo=0.3V 50 INPUT VOLTAGE: V_{I(on)} [V] 10 5 25°C 100°C 500m 200m 100μ 200μ 500μ 1m 5m 10m 20m 50m100m 2m OUTPUT CURRENT : Io [A]

(OFF characteristics) 10m Vcc=5V 5m 2m OUTPUT CURRENT : $I_{\rm o}$ [A] 1m **500**μ Ta=100°C 200_µ 25°C 40°C 100μ **50**μ 20_µ 10μ 5μ 2μ 1μL 0 0.5 1.5 2.0 3.0 1.0 INPUT VOLTAGE : V_{I(off)}[V]

Fig.2 Output current vs. input voltage

Fig.3 Output current vs. output voltage

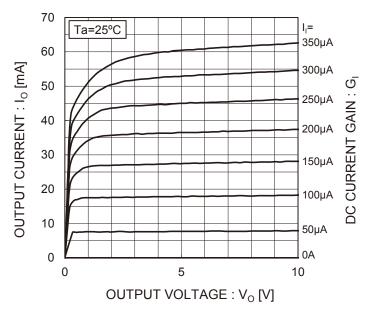
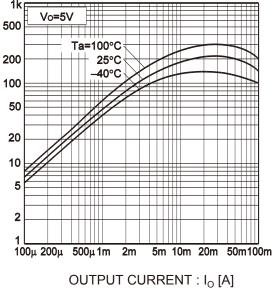
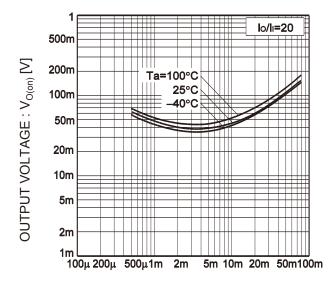


Fig.4 DC current gain vs. output current



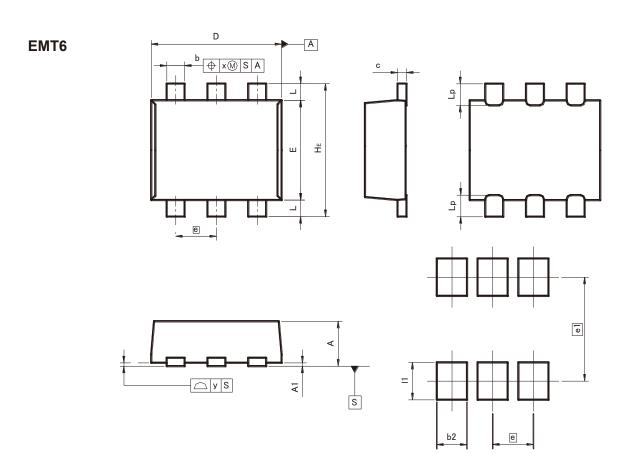
●Electrical characteristic curves(Ta = 25°C)

Fig.5 Output voltage vs. output current



OUTPUT CURRENT : I_O [A]

●Dimensions (Unit : mm)



Patterm of terminal position areas

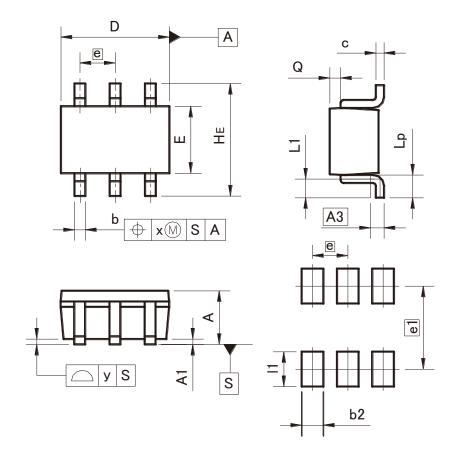
DIM	MILIMI	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
A1	0.00	0.10	0	0.004
Α	0.45	0.55	0.018	0.022
b	0.17	0.27	0.007	0.011
С	0.08	0.18	0.003	0.007
D	1.50	1.70	0.059	0.067
Е	1.10	1.30	0.043	0.051
е	0.9	50	0.0	02
HE	1.50	1.70	0.059	0.067
L	0.10	0.30	0.004	0.012
Lp	_	0.35	_	0.014
х	_	0.10		0.004
У	_	0.10	_	0.004

DIM	MILIMETERS		INCHES		
	MIN	MAX	MIN	MAX	
e1	1.3	25	0.049		
b2	- 0.37		ı	0.015	
11	_	0.45	_	0.018	

Dimension in mm/inches

●Dimensions (Unit : mm)

UMT6



Patterm of terminal position areas

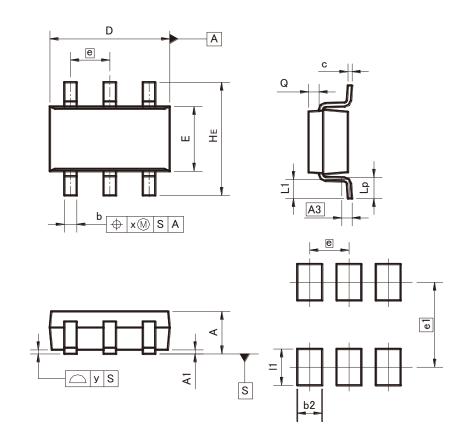
DIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	0.80	1.00	-	0.039	
A1	0.00	0.10	0	0.004	
A3	0.3	25	0.0	01	
b	0.15	0.30	0.006	0.012	
С	0.10	0.20	0.004	0.008	
D	1.90	2.10	0.075	0.083	
E	1.15	1.35	0.045	0.053	
е	0.0	65	0.03		
HE	2.00	2.20	0.079	0.087	
L1	0.20	0.50	0.008	0.02	
Lp	0.25	0.55	0.01	0.022	
Q	0.10	0.30	0.004	0.012	
Х	_	0.10	_	0.004	
У	_	0.10	_	0.004	

DIM	MILIMETERS		INCHES		
	MIN	MAX	MIN	MAX	
e1	1.	1.55		06	
b2	_	0.40	ı	0.016	
11	_	0.65	_	0.026	

Dimension in mm/inches

●Dimensions (Unit : mm)

SMT6



Patterm of terminal position areas

DIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	1.00	1.30	0.039	0.051	
A1	0.00	0.10	0	0.004	
A3	0.3	25	0.0	01	
b	0.25	0.40	0.01	0.016	
С	0.09	0.25	0.004	0.01	
D	2.80	3.00	0.11	0.118	
E	1.50	1.80	0.059	0.071	
е	0.9	95	0.04		
HE	2.60	3.00	0.102	0.118	
L1	0.30	0.60	0.012	0.024	
Lp	0.40	0.70	0.016	0.028	
Q	0.20	0.30	0.008	0.012	
х	_	0.20	_	0.008	
У		0.10	_	0.004	

	DIM	MILIMETERS		INCHES		
DIM		MIN	MAX	MIN	MAX	
	e1	2.10		0.08		
	b2	0.60		-	0.024	
	11	1	0.90	ı	0.035	

Dimension in mm/inches



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